
Proc. XIX International School of Semiconducting Compounds, Jaszowiec 1990

SPIN-DEPENDENT INTERACTION OF A BAND ELECTRON WITH PARAMAGNETIC IMPURITIES*

J. BLINOWSKI,

Institute of Theoretical Physics, Warsaw University, ul. Hoża 69, 00-681 Warsaw, Poland

AND P. KACMAN

Institute of Physics, Polish Academy of Sciences, al. Lotników 32/46, 02-668 Warsaw, Poland

(Received August 8, 1990)

A band electron interacting with N electrons in a d -shell of a paramagnetic impurity in zinc-blende type semiconductors was considered. The hybridization of band and d -states in the crystal field and the nonorthogonality mechanisms of interaction were examined in addition to the standard direct exchange. The Heisenberg-type form was derived for the interaction between a Γ_8 -electron and an impurity with a half-filled d -shell. The domination of the hybridization mechanism explains the observed sign of the effective exchange constant for Γ_8 electrons in diluted magnetic semiconductors (DMS) and the difference in magnitude of this constant for Mn^{2+} and Fe^{3+} ions in HgSe.

PACS numbers:75.50.Pp, 75.30.-m,71.70.-d

It is generally believed that the spin-dependent interaction of band electrons with paramagnetic ions in DMS can be described by an effective Heisenberg type Hamiltonian proportional to the product $\mathbf{S} \cdot \mathbf{J}$, where \mathbf{S} is the total spin operator of d -electrons and \mathbf{J} is the appropriate quasi-angular momentum for the band electron. Such a Hamiltonian has been rigorously derived from the direct exchange interaction for an electron in s -like bands (whatever the number of electrons in the d -shell of the paramagnetic ion) [1] and for an electron in Γ_8 bands in zinc-blende type crystals [2], but only in the case of a half filled d -shell. Incompatible with the direct exchange mechanism, experimental results for DMS gave a negative effective exchange constant β for Γ_8 bands.

*This work was partially supported by the Project CPBP 01.04

Guided by the results of [3], concerning a band electron interacting with an electron from a single d -orbital hybridized with the band, Bhattacharjee et al. [4] suggested that the antiferromagnetic interaction for a p band was due to strong p - d hybridization. In a more recent paper [5] Larson et al. gave support to this idea. They considered several d -orbitals hybridizing with the p -type Bloch functions but they used the band with well defined spin and a single hybridization matrix element independent of d - and p -orbitals involved. On the other hand, Semenov and Shanina [6] ascribed the antiferromagnetic interaction to the nonvanishing overlaps between the p -band and localized d -states.

It can be shown, that Γ_6 bands do not hybridize and have vanishing overlaps with d -orbitals, so that the direct exchange remains the only mechanism for s - d interaction.

Inspired by the controversy on the origins of the negative exchange constant β and by the new experimental results [7] indicating that β for Fe^{3+} ions in HgSe is much bigger than that for Mn^{2+} in the same compound, we decided to examine in detail the p - d interaction in zinc-blende type crystals. To account properly for the symmetry of the many-electron wave functions we use the occupation number representation. Our one-electron model Hamiltonian has the form $H = H_0 + H_1$

$$H_0 = \sum_{m,\sigma} \varepsilon_d \hat{n}_{m\sigma} + \sum_{n,k} \varepsilon_n(k) \hat{n}_{nk} \quad (1)$$

and

$$H_1 = \sum_{n,k,m,\sigma} [L_{m\sigma nk} \hat{a}_{m\sigma}^+ \hat{a}_{nk} + h.c.], \quad (2)$$

where $m = -2, -1, 0, 1, 2$ and $\sigma = \pm 1/2$ specify the states of a d -electron, whereas n and k define the Bloch functions of the band electron. The hybridization matrix elements are defined as $L_{m\sigma nk} = \langle m\sigma | V_{cf} | nk \rangle$, where V_{cf} is a crystal field potential, which in the range of localization of the d -electrons can be expressed as [8]

$$V_{cf} = F(r) \left\{ Y_{40}(\vartheta, \varphi) + \sqrt{5/14} [Y_{44}(\vartheta, \varphi) + Y_{4-4}(\vartheta, \varphi)] \right\} \quad (3)$$

$Y_{lm}(\vartheta, \varphi)$ are the spherical harmonics and $F(r)$ is the radial function.

We proved that even in the case of a nonorthogonal one-electron basis defining the occupation number representation, the one-particle Hamiltonian has only terms involving one creation and one annihilation operator. All terms proportional to matrix elements of the one-electron potential in [6] which involve two creation and two annihilation operators are incorrect. In fact they resulted from an arbitrary partial selection of terms in the one-electron Hamiltonian artificially expressed in the apparent form of a two particle operator. As a result of the same procedure the hybridization terms H_1 were lost in [6]. We proved that to the first order in overlap integrals the nonorthogonality of the one-electron basis gives only some corrections to hybridization matrix elements without changing the form of the Hamiltonian. Thus, in the following we will neglect these corrections.

H_1 couples the states of N d -electrons and 1 band electron with the states of $N+1$ (or $N-1$) d -electrons and 0 (or 2) band electrons. To describe properly the

energy differences between the coupled many particle states one should complete H_0 by the Coulomb interaction within the d -shell. The dominant effect of this interaction, i.e. the repulsion of opposite-spin electrons located on the same orbital, can be accounted for by the Anderson term [8]

$$(1/2) \sum_{m\sigma} U \hat{n}_{m\sigma} \hat{n}_{m-\sigma} \quad (4)$$

We eliminate H_1 to the first order in L adapting the canonical transformation of [3] to the case of 5 d -orbitals. To the second order in L the part of the transformed Hamiltonian, which depends on the state of d -electrons and is responsible for $\Gamma_8 \rightarrow \Gamma_8$ transitions in the vicinity of the Γ point, has the form

$$H_2 = \sum_{m\sigma, \sigma', m_j, k, m'_j, k'} L_{m\sigma m_j \sigma} L_{m\sigma' m'_j \sigma} \left[\frac{1}{\varepsilon_p - \varepsilon_d} - \frac{1}{\varepsilon_p - \varepsilon_d - U} \right] \times (\delta_{\sigma\sigma'} \hat{n}_{m-\sigma} + \delta_{-\sigma\sigma'} \hat{a}_{m\sigma}^+ \hat{a}_{m-\sigma}) \hat{a}_{m_j, k}^+ \hat{a}_{m'_j, k'}. \quad (5)$$

Here we passed to the Luttinger representation for the Γ_8 states, ε_p is the energy of the Γ_8 bands at $k = 0$.

To discuss sp - d interaction it is in the most cases enough to consider only the subspace of the lowest states of the paramagnetic ion given by Hund's rules. For ions like Mn^{2+} and Fe^{3+} with the half-filled d -shell (i.e. 6S ground term) the Hund's subspace is spanned by the vectors

$$|0, S\rangle = C \hat{S}_-^{5/2-S} \prod_{m=-2}^2 \hat{a}_{m\uparrow}^+ |0\rangle, \quad S = \mp \frac{5}{2}, \mp \frac{3}{2}, \mp \frac{1}{2}; \quad (6)$$

where $\hat{S}_- = \sum_{m=-2}^2 \hat{a}_{m\downarrow}^+ \hat{a}_{m\uparrow}$ is the spin lowering operator, $|0\rangle$ is the vacuum state and C is the normalization constant depending on S .

We established that the Hamiltonian (5) leads to the Heisenberg-type p - d interaction only for the 6S ions. The obtained negative effective exchange constant

$$J_{ex} = -(2/5) L_{2\uparrow, \frac{1}{2}\sigma}^2 \left[\frac{1}{\varepsilon_p - \varepsilon_d} + \frac{1}{\varepsilon_d + U - \varepsilon_p} \right] \quad (7)$$

has a similar form to that proposed in [4] and [5] but the present formula gives a precise definition for the vaguely defined there hybridization matrix element V_{kd} .

We notice, that the first energy denominator in formula (7) represents the energy which has to be supplied when one electron is taken from the half-filled d -shell and put into the band. The second one is the energy required when transferring the band electron into the already half-filled d -shell. As the latter energy is particularly small for iron impurities in HgSe [10], one can easily conclude that the observed difference in magnitude of the exchange constants for Mn^{2+} and Fe^{3+} in HgSe can result from the changes in energy denominators in formula (7).

References

- [1] S.H. Liu, *Phys. Rev.* **121**, 451 (1961).
- [2] J.Kossut, in *Semiconductors and Semimetals*, Vol.25, *Diluted Magnetic Semiconductors*, ed. J.K.Furdyna, J. Kossut, Academic Press, San Diego 1988, p. 183.
- [3] J.R. Schrieffer, P.A. Wolff, *Phys.Rev.* **149**, 491 (1966).
- [4] A.K. Bhattacharjee, G. Fishman, B. Coqblin, *Physica B* **117 - 118**, 449 (1983).
- [5] B.E. Larson, K.C. Hass, H. Ehrenreich, A.E. Carlsson, *Phys. Rev. B* **37**, 4137 (1988).
- [6] Y.G. Semenov, B.D. Shanina, *Phys. Status Solidi B* **104**, 631 (1981).
- [7] Z. Wilamowski, A. Mycielski, W. Jantch, G.Hendorfer, *Phys.Rev B* **38**, 3621 (1988).
- [8] G.A. Slack, S. Roberts, J.T. Vallin, *Phys. Rev.* **187**, 511 (1969).
- [9] P.W. Anderson, *Phys. Rev.* **124**, 41 (1961).
- [10] A. Mycielski, *J. Appl. Phys.* **63**, 3279 (1988).